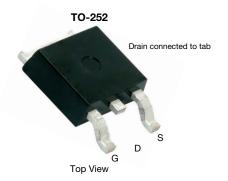


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Automotive N-Channel 60 V (D-S) 175 °C MOSFET

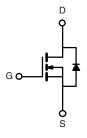
PRODUCT SUMMARY d				
V _{DS} (V)	60			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.042			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 \text{ V}$	0.060			
I _D (A)	15			
Configuration	Single			
Package	TO-252			



FEATURES

- TrenchFET® power MOSFET
- 100 % R_g and UIS tested
- AEC-Q101 qualified
- Package with low thermal resistance
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current	T _C = 25 °C ^a	- I _D	15		
	T _C = 125 °C		10		
Continuous Source Current (Diode Conduction) ^a		Is	15	Α	
Pulsed Drain Current ^b		I _{DM}	50		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	18		
Single Pulse Avalanche Energy	L = 0.1 IIII	E _{AS}	16.2	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	- P _D	37	W	
	T _C = 125 °C		11	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount c	R_{thJA}	50	°C/W	
Junction-to-Case (Drain)		R _{thJC}	4	G/W	

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- c. When mounted on 1" square PCB (FR4 material).

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static						ı	
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		60	-	-	V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	· V _{GS} , I _D = 250 μA	1.5	2	2.5] V
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 60 V	i	-	1	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 125 °C	1	-	50	μΑ
		$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 175 °C	1	-	150]
On-State Drain Current ^a	I _{D(on)}	$V_{GS} = 10 \text{ V}$	$V_{DS} \ge 5 V$	30	-	-	Α
		V _{GS} = 10 V	I _D = 10 A	1	0.036	0.042	
		$V_{GS} = 10 \text{ V}$	I _D = 10 A, T _J = 125 °C	ı	-	0.075	
Drain-Source On-State Resistance ^a	D	$V_{GS} = 10 \text{ V}$	I _D = 10 A, T _J = 175 °C	i	-	0.090	Ω
Drain-Source On-State Resistance	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}$	I _D = 10 A, T _J = 125 °C	-	0.092	-	1 32
		$V_{GS} = 4.5 \text{ V}$	I _D = 10 A, T _J = 175 °C	-	0.110	-	•
		$V_{GS} = 4.5 \text{ V}$	I _D = 10 A	=	0.048	0.060]
Forward Transconductance b	9 _{fs}	$V_{DS} = 15 \text{ V}, I_D = 6 \text{ A}$		-	11	-	S
Dynamic ^b							
Input Capacitance	C _{iss}			i	425	535	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	-	95	120	pF
Reverse Transfer Capacitance	C _{rss}			1	40	50	
Total Gate Charge ^c	Qg			i	9.5	15	
Gate-Source Charge ^c	Q_{gs}	$V_{GS} = 10 \text{ V}$	$V_{DS} = 30 \text{ V}, I_{D} = 15 \text{ A}$	-	1.7	-	nC
Gate-Drain Charge ^c	Q_{gd}				2.5	-	
Gate Resistance	R_g		f = 1 MHz		2.5	5.4	Ω
Turn-On Delay Time ^c	t _{d(on)}	$V_{DD} = 30 \text{ V, } R_L = 2 \Omega$ $I_D \cong 15 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 1 \Omega$		-	5	8	
Rise Time ^c	t _r			-	10	15	- ns
Turn-Off Delay Time ^c	t _{d(off)}			-	13	20	
Fall Time ^c	t _f			=	8	12	
Source-Drain Diode Ratings and Chara	icteristics ^b						
Pulsed Current ^a	I _{SM}			-	-	50	Α
Forward Voltage	V _{SD}	I _F =	10 A, V _{GS} = 0 V	=	0.9	1.2	V
Reverse Recovery Time	t _{rr}	I _F = 15 A, dI/dt = 100 A/μs		-	29	60	ns

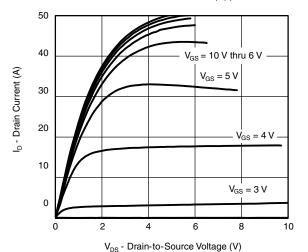
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

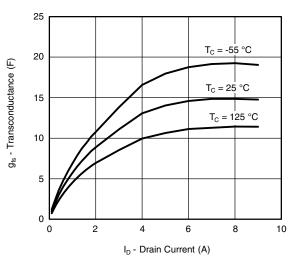
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



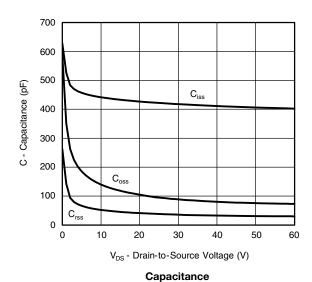
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

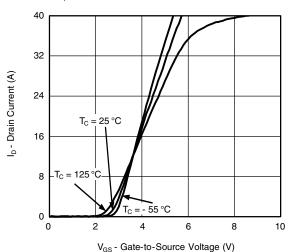


Output Characteristics

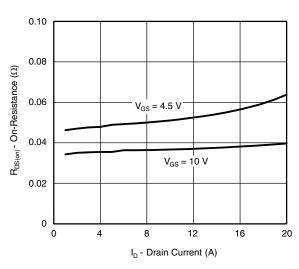


Transconductance

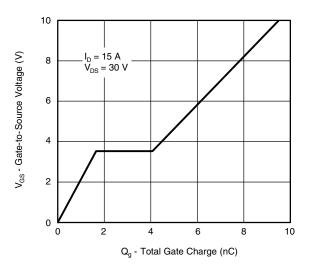




Transfer Characteristics

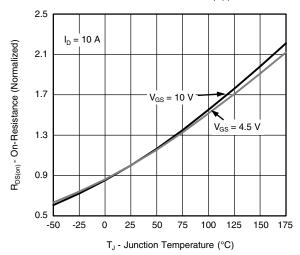


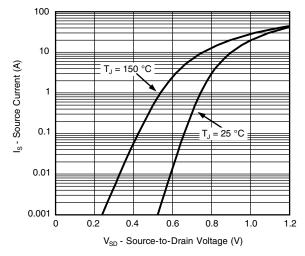
On-Resistance vs. Drain Current



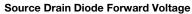


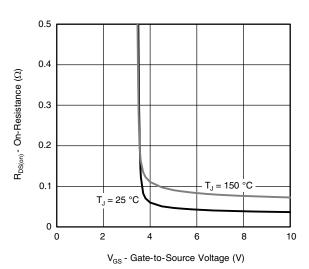
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

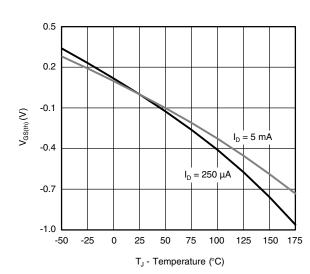




On-Resistance vs. Junction Temperature

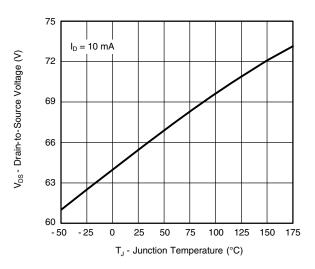






On-Resistance vs. Gate-to-Source Voltage

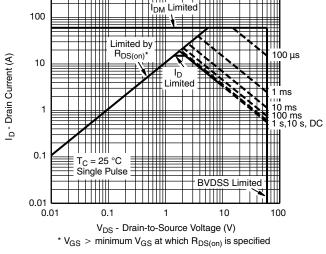
Threshold Voltage



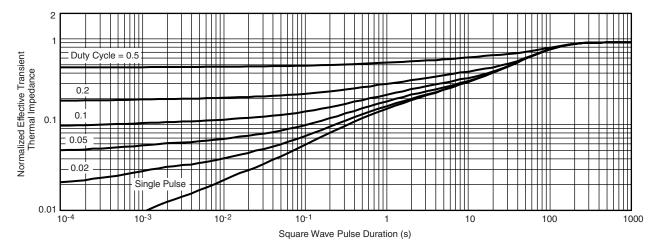
On-Resistance vs. Junction Temperature



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



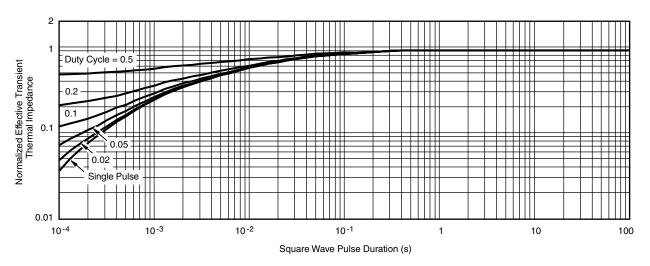
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg268880.



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REVISION HISTORY a				
REVISION	DATE	DESCRIPTION OF CHANGE		
G	04-Aug-15	Revised R _g minimum limit		

Note

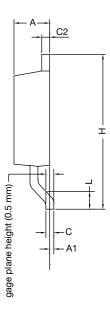
a. As of April 2014



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TO-252AA Case Outline





	MILLIMETERS		INCHES	
DIM.	MIN.	MAX.	MIN.	MAX.
Α	2.18	2.38	0.086	0.094
A1	-	0.127	-	0.005
b	0.64	0.88	0.025	0.035
b2	0.76	1.14	0.030	0.045
b3	4.95	5.46	0.195	0.215
С	0.46	0.61	0.018	0.024
C2	0.46	0.89	0.018	0.035
D	5.97	6.22	0.235	0.245
D1	4.10	-	0.161	-
E	6.35	6.73	0.250	0.265
E1	4.32	-	0.170	-
Н	9.40	10.41	0.370	0.410
е	2.28 BSC		0.090 BSC	
e1	4.56 BSC		0.180 BSC	
L	1.40	1.78	0.055	0.070
L3	0.89	1.27	0.035	0.050
L4	-	1.02	-	0.040
L5	1.01	1.52	0.040	0.060
ECN: T13-0592-Rev. A, 02-Sep-13 DWG: 6019				

Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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